

EEE 425/591

HW2 Solutions

Q1 a) $C_{ox} = \frac{\epsilon_{ox}}{t_{ox}} = \frac{3.9 \times 8.85 \times 10^{-12} \text{ F/m}}{9 \times 10^{-9} \text{ m}} = 3.8 \times 10^3 \text{ F/m}^2$

b) $k_n = \mu_n C_{ox} \frac{W_n}{L_n} = 0.056 \frac{\text{m}^2}{\text{Vs}} \times 3.8 \times 10^3 \frac{\text{F}}{\text{m}^2} \times \frac{2 \mu\text{m}}{0.25 \mu\text{m}}$
 $= 1.7 \text{ mA/V}^2$

c) Transistor in linear region

$$C_{gd} = C_{ox} \frac{WL}{2} + C_o W$$

$$= 3.8 \times 10^{-15} \frac{\text{F}}{\mu\text{m}^2} \times \frac{2 \mu\text{m} \times 0.25 \mu\text{m}}{2} + 0.4 \times 10^{-15} \frac{\text{F}}{\mu\text{m}} \times 2 \mu\text{m}$$

$$= 1.76 \text{ fF}$$

$$C_{gs} \approx C_{gd} = 1.76 \text{ fF}$$

$$C_{dbso} = (2 \mu\text{m})(0.6 \mu\text{m}) \times 1.7 \frac{\text{fF}}{\mu\text{m}^2} = 2.04 \text{ fF}$$

$$C_{dbsw0} = (2 \mu\text{m} + 2 \times 0.6 \mu\text{m}) \times \frac{0.4 \text{ fF}}{\mu\text{m}} = 1.28 \text{ fF}$$

$$C_{db} = \frac{2.04 \text{ fF}}{(2.25)^{1/2}} + \frac{1.28 \text{ fF}}{(2.25)^{1/3}} = 2.34 \text{ fF}$$

Q2 $W_n = 0.36$ $W_p = 0.8$

a) $r = \sqrt{\frac{M_p W_p}{M_n W_n}} = \sqrt{\frac{220 \times 0.8}{560 \times 0.36}} = 0.93$

$V_M = \frac{0.6 + 0.93(2.5 - 0.6)}{1 + 0.93} = 1.23V$

b) $R_n = \frac{1}{k_n \frac{W_n}{L} (V_{DD} - V_T)} = \frac{1}{0.56 \times \frac{0.36}{0.25} \times (2.5 - 0.6)} k\Omega$

$R_n = 0.65 k\Omega$

$R_p = \frac{1}{0.22 \left(\frac{0.8}{0.25}\right) (1.9)} k\Omega = 0.75 k\Omega$

c) R_n remains the same $W_n = 0.36$

$W_p = W_n \frac{M_n}{M_p} = 0.36 \times \frac{56}{22} = 0.92 \mu m$

d) $C_{g\text{tot}} = (W_p + W_n) C_{ov} = (0.36 + 0.8) \times 10^{-6} \times 0.4 \times 10^{-9} F$
 $= 0.46 fF$

$C_{dbpjo} = W_p C_{j0} = (0.8 \mu m \times 0.6 \mu m) \times \frac{1.7 fF}{\mu m^2} = 0.82 fF$

$C_{dbnjo} = 0.37 fF$

$C_{dbpswo} = (W_p + 2L_s) C_{jsw0} = (2 \mu m) \times 0.4 fF/\mu m = 0.8 fF$

$C_{dbnswo} = (W_n + 2L_s) C_{jsw0} = (1.56 \mu m) \times 0.4 fF/\mu m = 0.6 fF$

$$C_{TOT} = \underset{\substack{\uparrow \\ \text{load}}}{74 \text{ fF}} + \frac{0.82 \text{ fF} + 0.37 \text{ fF}}{\substack{\uparrow \\ \text{bottom}}{\sqrt{1 + \frac{1.25}{1}}}} + \frac{0.8 \text{ fF} + 0.6 \text{ fF}}{\substack{\uparrow \\ \text{signal}}{(1 + 1.25)^{1/3}}} + 2 \times \underset{\substack{\uparrow \\ \text{2Cgd}}}{0.46 \text{ fF}}$$

$$(74 + 0.79 + 1.07 + 0.92) \text{ fF} = 76.8 \text{ fF}$$

$$t_{pHL} = 0.2 \times 0.65 \text{ k} \times 76.8 \text{ fF} = 24.9 \text{ ps}$$

$$t_{pLH} = 0.7 \times 0.75 \text{ k} \times 76.8 \text{ fF} = 40.3 \text{ ps}$$

③ Delay doubles when $(V_{DD} - V_T)$ reduces to half of its value

$$V_{DD_{new}} - V_T = \frac{1}{2} (2.5 - 0.6)$$

$$V_{DD} = 1.55 \text{ V}$$

Q3

a) $V_{in} = V_{DD} \rightarrow$ PMOS leaks

$$V_{S6} = 0 \quad V_{SD} = V_{DD}$$

$$I_{leakp} = \frac{W_p}{L_p} I_0 e^{\frac{-V_{th}}{V_T}} (1 - e^{\frac{-V_{DD}}{V_T}})$$

$$= 2.5 \times 10^{-7} e^{\frac{-600}{3 \times 25}} = 8.4 \times 10^{-11} \text{ A}$$

$$P_{leak} = 2.1 \times 10^{-10} \text{ W}$$

$V_{in} = 0 \rightarrow$ NMOS leaks

$$I_{leakn} = I_{leakp} \times \frac{W_n}{W_p} = 3.4 \times 10^{-11} \text{ A}$$

$$P_{leakn} = 8.4 \times 10^{-11} \text{ W}$$

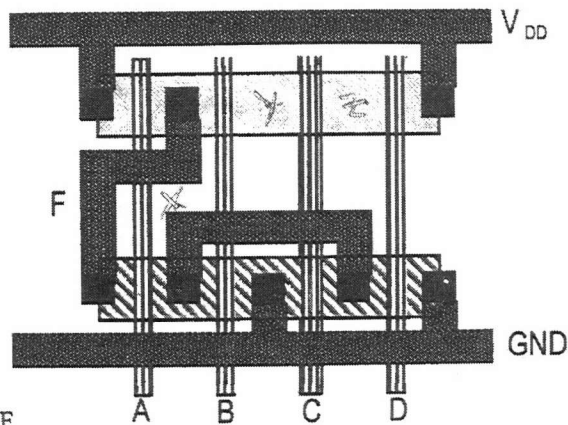
$$b) E = CV_{DD}^2 = 50 \times 10^{-15} \times (2.5)^2 = 0.3 \times 10^{-12} \text{ J}$$

c) Total leakage energy

$$= P_{leakp} \times 100 \text{ ns} + P_{leakn} \times 100 \text{ ns}$$

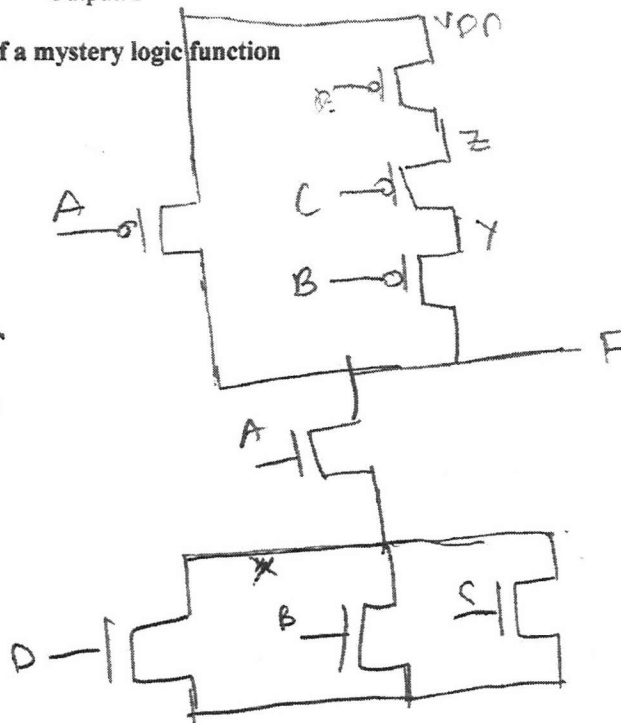
$$= 2.1 \times 10^{-11} \times 10^{-7} + 8.4 \times 10^{-11} \times 10^{-7} = 29.4 \times 10^{-18} \text{ J}$$

Q4



Inputs: A, B, C, D Output: F

Figure 1: Layout of a mystery logic function



$$F = \bar{A} + \bar{B}\bar{C}\bar{D}$$

$$A=0 \rightarrow F=1$$

A	B	C	D	F
1	0	0	0	1
1	0	0	1	0
1	0	1	0	0
1	0	1	1	0
1	1	0	0	0
1	1	0	1	0
1	1	1	0	0
1	1	1	1	0